



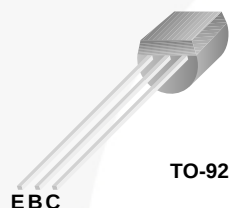
October 2014

2N3904 / MMBT3904 / PZT3904 NPN General-Purpose Amplifier

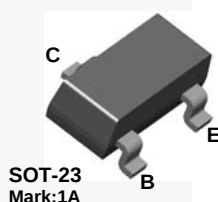
Description

This device is designed as a general-purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

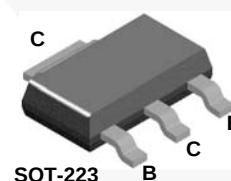
2N3904



MMBT3904



PZT3904



Ordering Information

Part Number	Marking	Package	Packing Method	Pack Quantity
2N3904BU	2N3904	TO-92 3L	Bulk	10000
2N3904TA	2N3904	TO-92 3L	Ammo	2000
2N3904TAR	2N3904	TO-92 3L	Ammo	2000
2N3904TF	2N3904	TO-92 3L	Tape and Reel	2000
2N3904TFR	2N3904	TO-92 3L	Tape and Reel	2000
MMBT3904	1A	SOT-23 3L	Tape and Reel	3000
PZT3904	3904	SOT-223 4L	Tape and Reel	2500

2N3904 / MMBT3904 / PZT3904 — NPN General-Purpose Amplifier

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current - Continuous	200	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	$^\circ\text{C}$

Notes:

- These ratings are based on a maximum junction temperature of 150°C .
- These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Maximum			Unit
		2N3904	MMBT3904 ⁽³⁾	PZT3904 ⁽⁴⁾	
P_D	Total Device Dissipation	625	350	1,000	mW
	Derate Above 25°C	5.0	2.8	8.0	mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	$^\circ\text{C/W}$

Notes:

- Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.
- Device is mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm, mounting pad for the collector lead minimum 6 cm^2 .

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
OFF CHARACTERISTICS					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1.0 mA, I _B = 0	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA, I _E = 0	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	6.0		V
I _{BL}	Base Cut-Off Current	V _{CE} = 30 V, V _{EB} = 3 V		50	nA
I _{CEX}	Collector Cut-Off Current	V _{CE} = 30 V, V _{EB} = 3 V		50	nA
ON CHARACTERISTICS ⁽⁵⁾					
h _{FE}	DC Current Gain	I _C = 0.1 mA, V _{CE} = 1.0 V	40		
		I _C = 1.0 mA, V _{CE} = 1.0 V	70		
		I _C = 10 mA, V _{CE} = 1.0 V	100	300	
		I _C = 50 mA, V _{CE} = 1.0 V	60		
		I _C =100 mA, V _{CE} = 1.0V	30		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA		0.2	V
		I _C = 50 mA, I _B = 5.0 mA		0.3	
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA	0.65	0.85	V
		I _C = 50 mA, I _B = 5.0 mA		0.95	
SMALL SIGNAL CHARACTERISTICS					
f _T	Current Gain - Bandwidth Product	I _C = 10 mA, V _{CE} = 20 V, f = 100 MHz	300		MHz
C _{obo}	Output Capacitance	V _{CB} = 5.0 V, I _E = 0, f = 100 kHz		4.0	pF
C _{ibo}	Input Capacitance	V _{EB} = 0.5 V, I _C = 0, f = 100 kHz		8.0	pF
NF	Noise Figure	I _C = 100 μA, V _{CE} = 5.0 V, R _S = 1.0 kΩ, f = 10 Hz to 15.7 kHz		5.0	dB
SWITCHING CHARACTERISTICS					
t _d	Delay Time	V _{CC} = 3.0 V, V _{BE} = 0.5 V I _C = 10 mA, I _{B1} = 1.0 mA		35	ns
t _r	Rise Time			35	ns
t _s	Storage Time	V _{CC} = 3.0 V, I _C = 10 mA, I _{B1} = I _{B2} = 1.0 mA		200	ns
t _f	Fall Time			50	ns

Note:

5. Pulse test: pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2.0\%$.

Typical Performance Characteristics

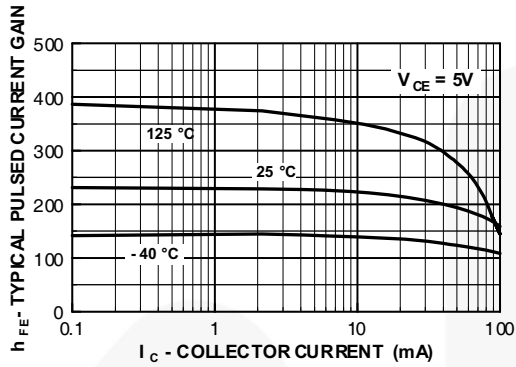


Figure 1. Typical Pulsed Current Gain vs. Collector Current

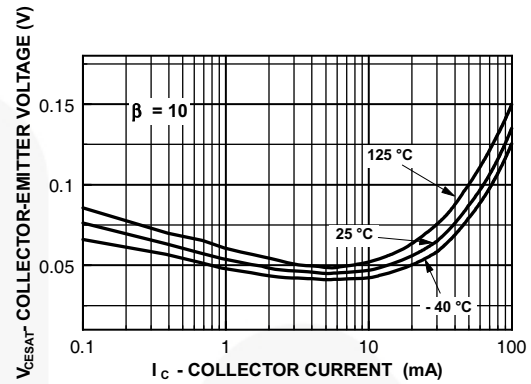


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

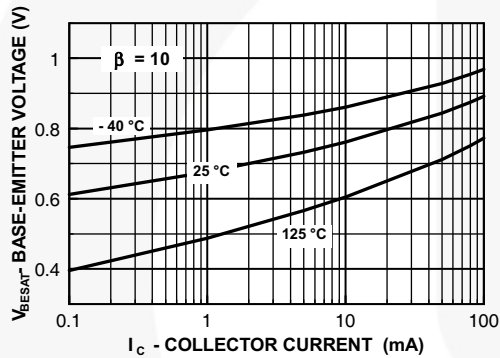


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

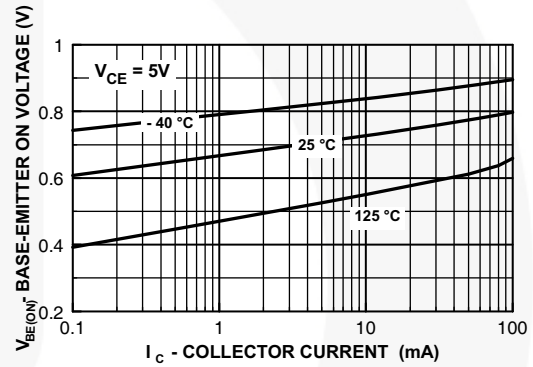


Figure 4. Base-Emitter On Voltage vs. Collector Current

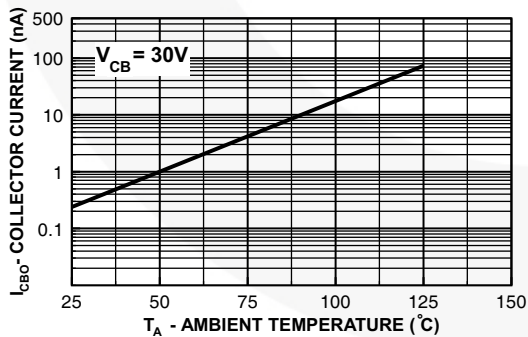


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

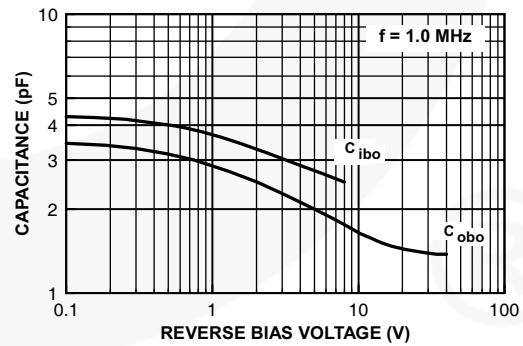


Figure 6. Capacitance vs. Reverse Bias Voltage

Typical Performance Characteristics (Continued)

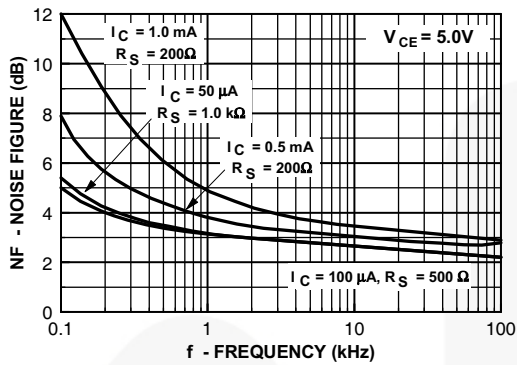


Figure 7. Noise Figure vs. Frequency

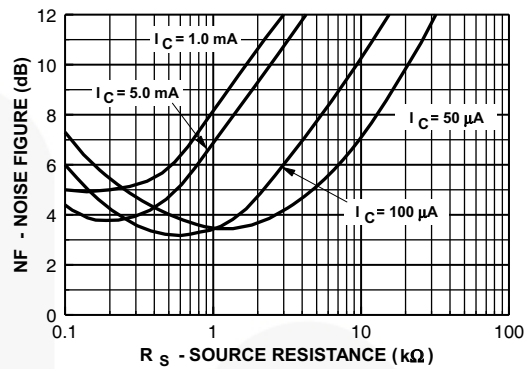


Figure 8. Noise Figure vs. Source Resistance

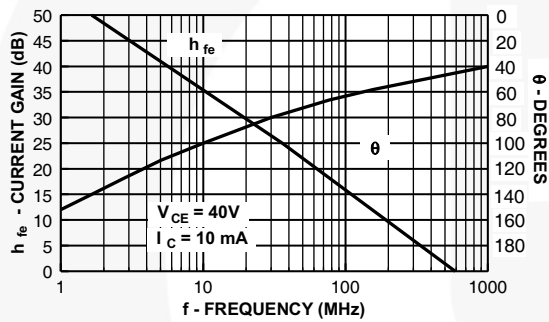


Figure 9. Current Gain and Phase Angle vs. Frequency

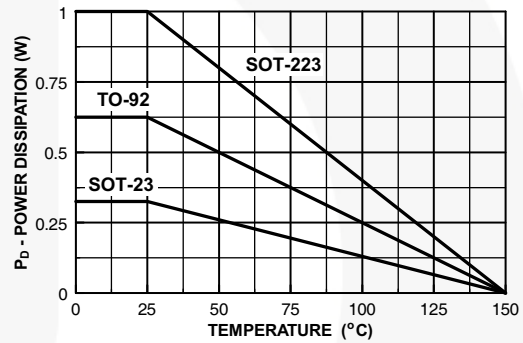


Figure 10. Power Dissipation vs. Ambient Temperature

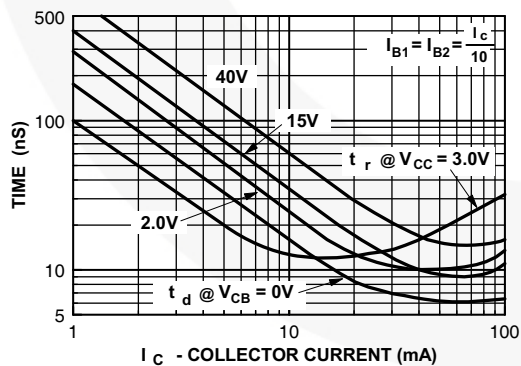


Figure 11. Turn-On Time vs. Collector Current

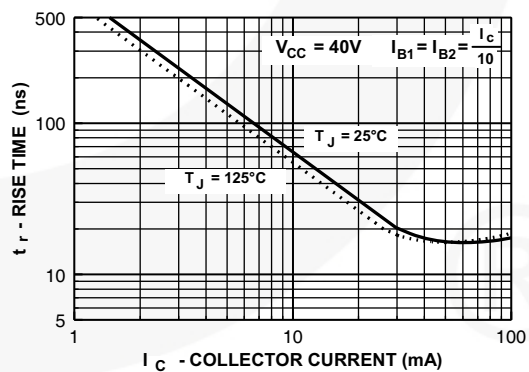


Figure 12. Rise Time vs. Collector Current

Typical Performance Characteristics (Continued)

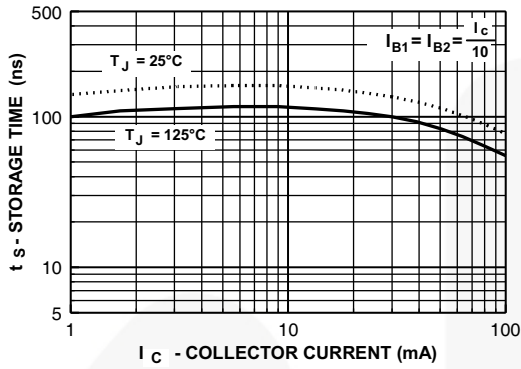


Figure 13. Storage Time vs. Collector Current

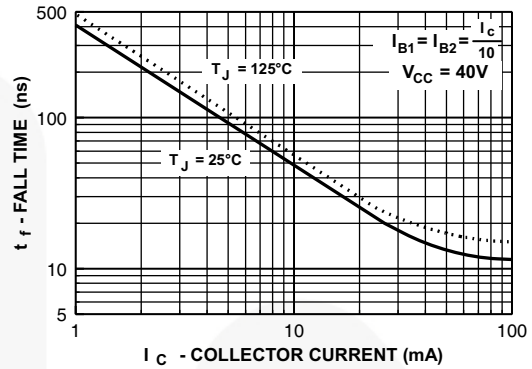


Figure 14. Fall Time vs. Collector Current

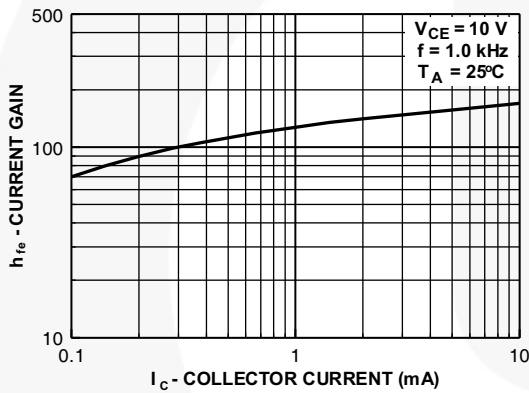


Figure 15. Current Gain

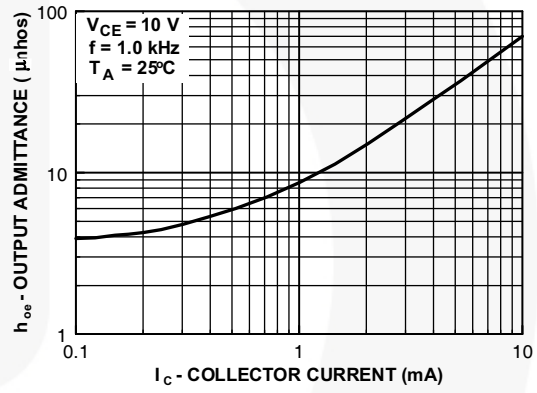


Figure 16. Output Admittance

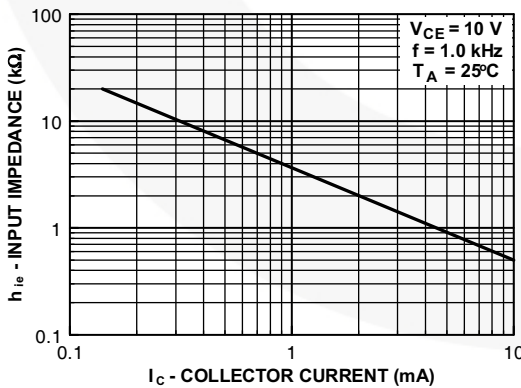


Figure 17. Input Impedance

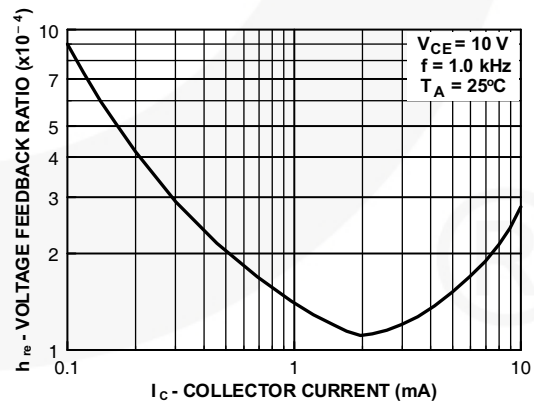


Figure 18. Voltage Feedback Ratio

Test Circuits

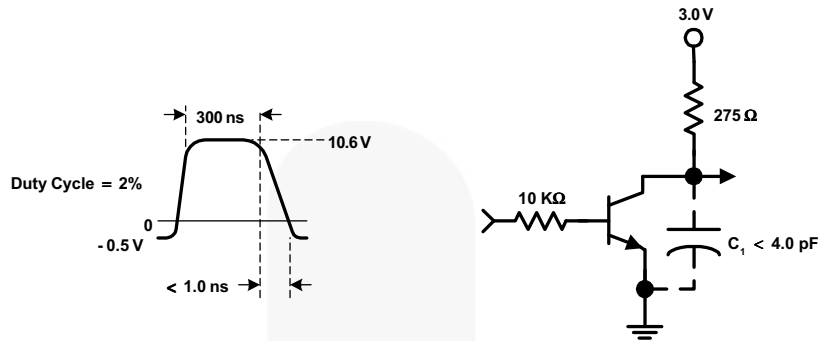


Figure 19. Delay and Rise Time Equivalent Test Circuit

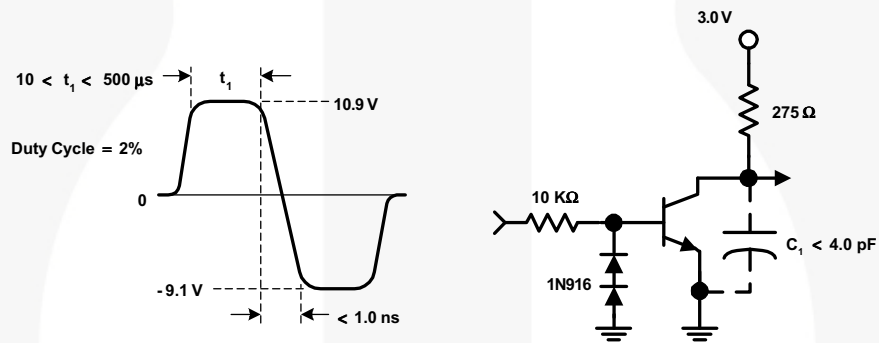
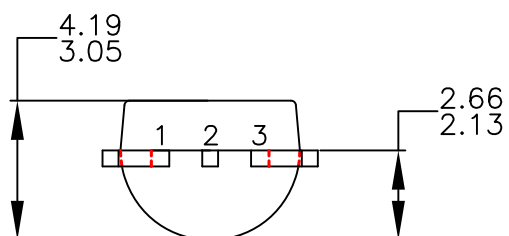
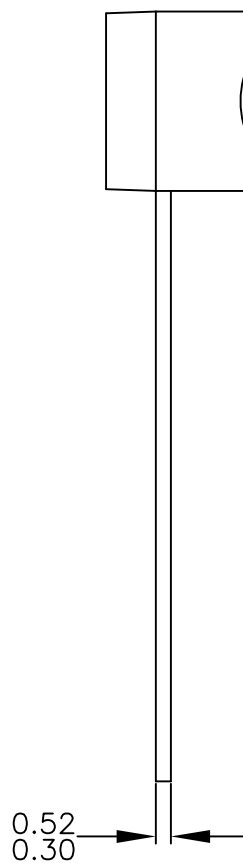
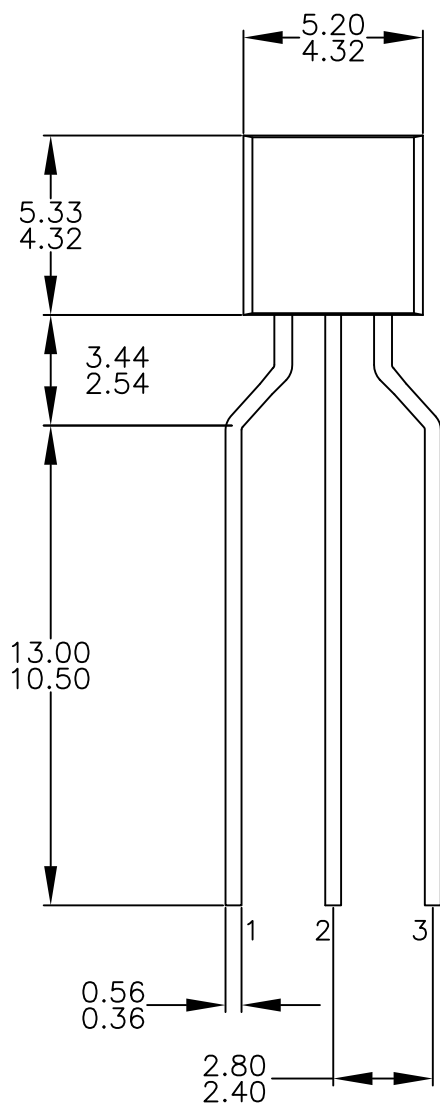
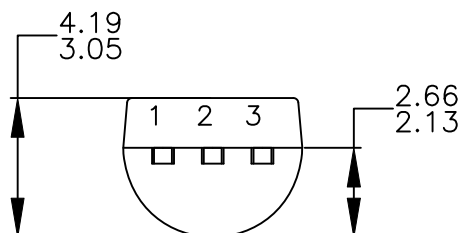
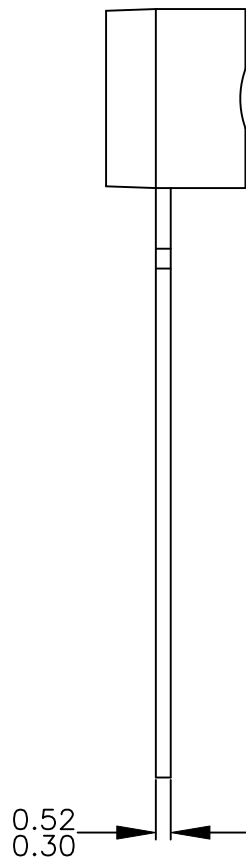
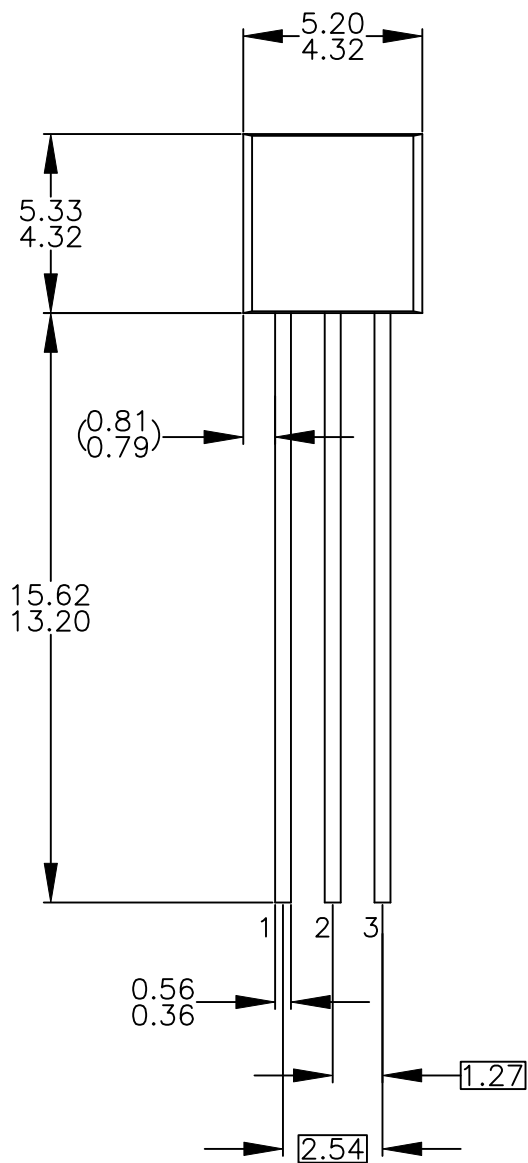


Figure 20. Storage and Fall Time Equivalent Test Circuit



NOTES: UNLESS OTHERWISE SPECIFIED

- A. DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5M-2009.
- D. DRAWING FILENAME: MKT-ZA03FREV3.
- E. FAIRCHILD SEMICONDUCTOR.



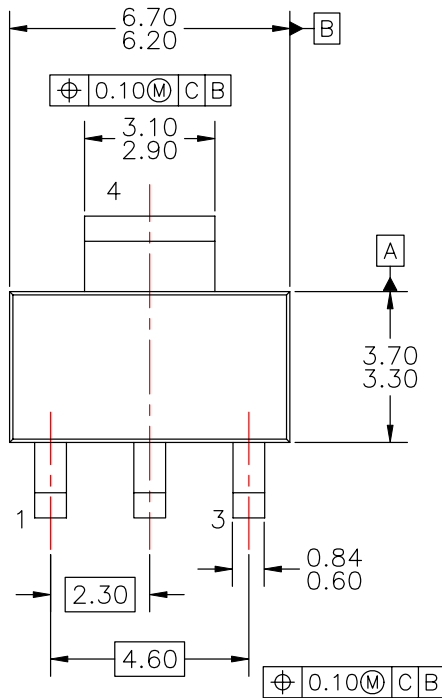
NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-2009.
- D) DRAWING FILENAME: MKT-ZA03DREV4.

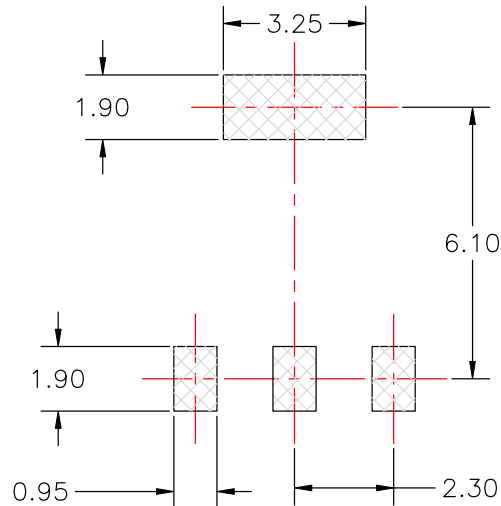


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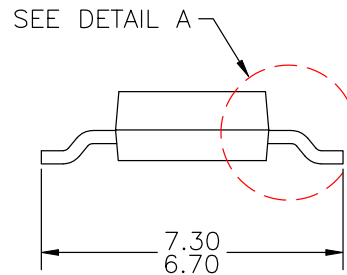
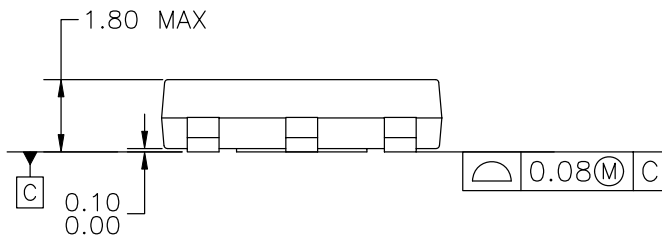
APPROVED
July-14-2008



REVISIONS			
LTR	DESCRIPTION	DATE	NAME/SITE
A	RELEASE TO DOCUMENT CONTROL	JAN.25.1996	TL/FSCP
2	CHG DWG TEMPLATE FR NATIONAL TO FAIRCHILD; CHG DIM STYLE FR DUAL INCH[MM] TO SINGLE, MM; CHG LD WID FR 0.74 $\pm$ 0.05 TO 0.60-0.84; REMOVE PKG THICK DIM (1.6); CHG TOTAL PKG HT FR 1.80 TO 1.80 MAX; CHG FOOT LANDING DIM FR 0.91 MIN TO 0.60 MIN; CHG LD THICKNESS FR 0.35 $\pm$ 0.08 TO 0.20-0.35; ADD DRAFT ANGLE OF MOLDED BODY TOP & BOT; CHG LD LGTH TO PKG EDGE DIM TO BASIC; CHG LD PITCH FR 2.29 BS TO 2.30 BS; CHG BODY WID FR 3.56 $\pm$ 0.38 TO 3.30; CHG BODY LN FR 6.55 $\pm$ 0.38 TO 6.30; CHG TOTAL PKG WID FR 6.94 $\pm$ 0.38 TO 7.30; CHG PAD SIZE FR 0.99 MAX TO 0.95; CHG PAD PITCH FR 2.286 TO 2.30; CHG THERMAL TAB SIZE FR 3.28 MAX TO 3.25; CHG PAD SIZE FR 1.5 TO 1.90; CHG PAD SPACE FR 6.3 TO 6.10; CHG NOTE '2' TO 'A' W/O DATE; DEL NOTE ON LD FINISH; ADD NOTES B, C, D, E & F.	12FEB08	LZSC/FSCP

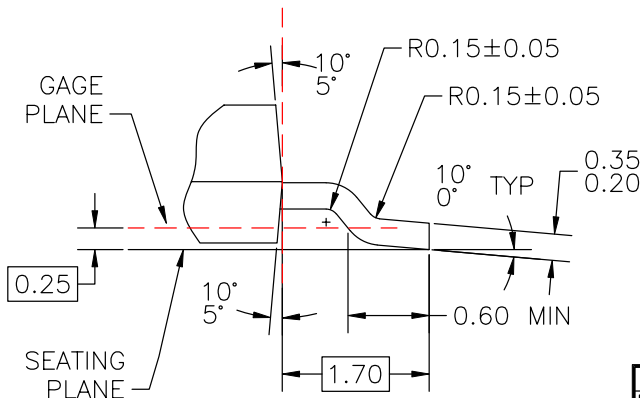


LAND PATTERN RECOMMENDATION



NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING BASED ON JEDEC REGISTRATION TO-261, VARIATION AA.
- B) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- C) ALL DIMENSIONS ARE IN MILLIMETERS.
- D) DRAWING CONFORMS TO ASME Y14.5M-1994.
- E) LANDPATTERN NAME: SOT230P700X180-4BN
- F) DRAWING FILENAME: MKT-MA04AREV2



DETAIL A
SCALE: 2:1

APPROVALS		DATE	FAIRCHILD SEMICONDUCTOR™		
DRAWN: J.U. COMPARATIVO JR.		26FEB2008			
CHECKED: L.Z. STA CRUZ					
APPROVED: M.R. GESTOLE		MOLDED PACKAGE SOT-223, 4 LEAD			
G.S. BAJE					
PROJECTION 					
INCH		SCALE 1:1	SIZE A3	DRAWING NUMBER MKT-MA04A	REV 2
FORMERLY: N/A		SHEET : 1 OF 1			



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IntelliMAX™
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MicroFET™
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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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